# RENESAS

# RJK03L3DNS

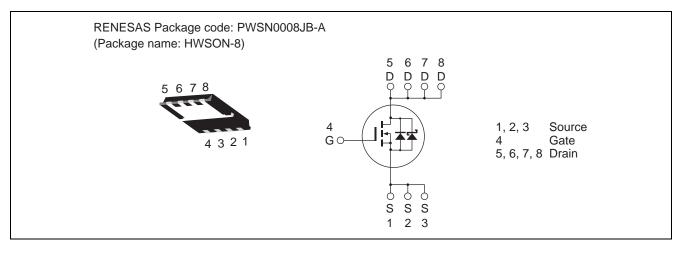
Silicon N Channel Power MOS FET with Schottky Barrier Diode Power Switching R07DS0780EJ0110 Rev 1 10

Rev.1.10 May 30, 2012

## Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance  $R_{DS(on)} = 5.3 \text{ m}\Omega \text{ typ.} (\text{at } V_{GS} = 10 \text{ V})$
- Pb-free
- Halogen-free

### Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$	
Item	Symbol	Ratings	Unit	
Drain to source voltage	V <sub>DSS</sub>	30	V	
Gate to source voltage	V <sub>GSS</sub>	±20	V	
Drain current	ID	25	А	
Drain peak current	Note1	100	А	
Body-drain diode reverse drain current	I <sub>DR</sub>	25	А	
Avalanche current	AP Note 2	10.5	А	
Avalanche energy	E <sub>As</sub> Note 2	11	mJ	
Channel dissipation	Pch Note3	15	W	
Channel to case thermal impedance	θch-c <sup>Note3</sup>	8.33	°C/W	
Channel temperature	Tch	150	٥°	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tch = 25°C, Rg  $\ge$  50  $\Omega$ 

3. Tc = 25°C



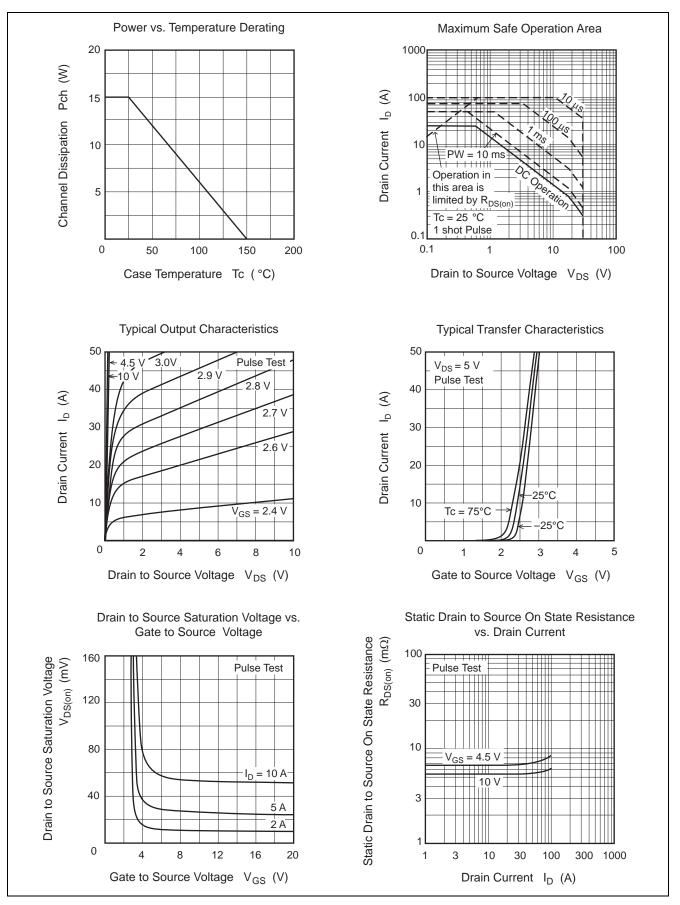
## **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	—	—	±0.5	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	—	1	mA	$V_{DS} = 24 V, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	5.3	6.4	mΩ	$I_D = 12.5A, V_{GS} = 10 V^{Note4}$
resistance	R <sub>DS(on)</sub>	_	6.7	8.7	mΩ	$I_D = 12.5A, V_{GS} = 4.5 V^{Note4}$
Forward transfer admittance	y <sub>fs</sub>	_	50	_	S	$I_D = 12.5A, V_{DS} = 5 V^{Note4}$
Input capacitance	Ciss	_	1550	2170	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	265	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	155	_	pF	
Gate Resistance	Rg		1.7	3.4	Ω	
Total gate charge	Qg		12.3		nC	$V_{DD} = 10 V$ $V_{GS} = 4.5 V$ $I_D = 25 A$
Gate to source charge	Qgs		4.0	_	nC	
Gate to drain charge	Qgd	_	3.7	—	nC	
Turn-on delay time	t <sub>d(on)</sub>		3.9	—	ns	$V_{GS} = 10 \text{ V}, I_D = 12.5 \text{ A}$
Rise time	tr		3.7		ns	$V_{DD} \cong 10 \text{ V}$ $R_{L} = 0.8 \Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t <sub>d(off)</sub>		29		ns	
Fall time	t <sub>f</sub>		9.4		ns	
Body-drain diode forward voltage	$V_{DF}$		0.47		V	$I_F = 2 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t <sub>rr</sub>		6.4		ns	I <sub>F</sub> =25 A, V <sub>GS</sub> = 0
time						di <sub>F</sub> / dt = 500 A/ μs

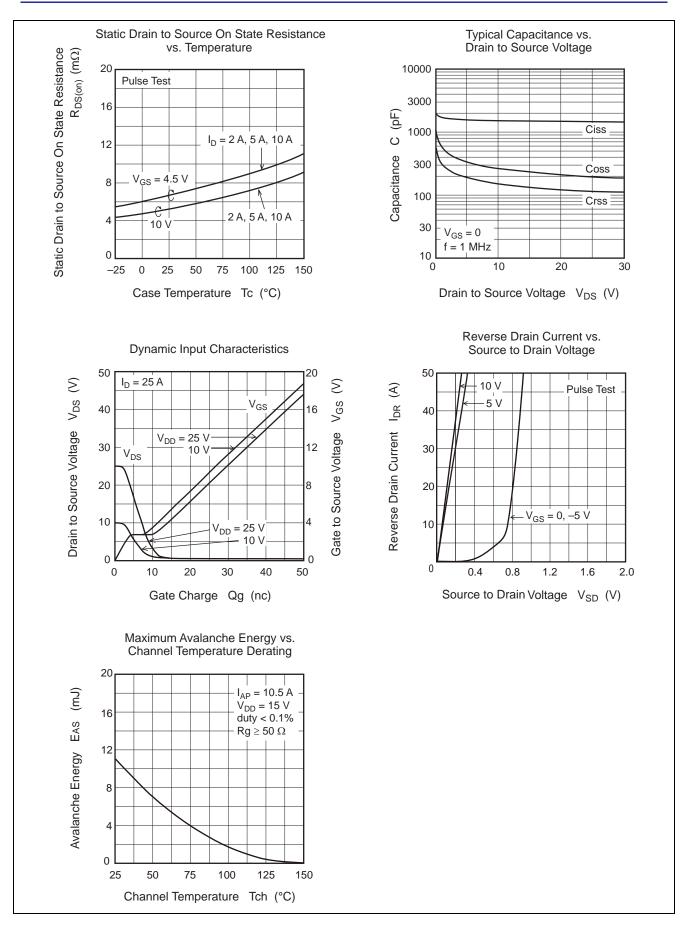
Notes: 4. Pulse test



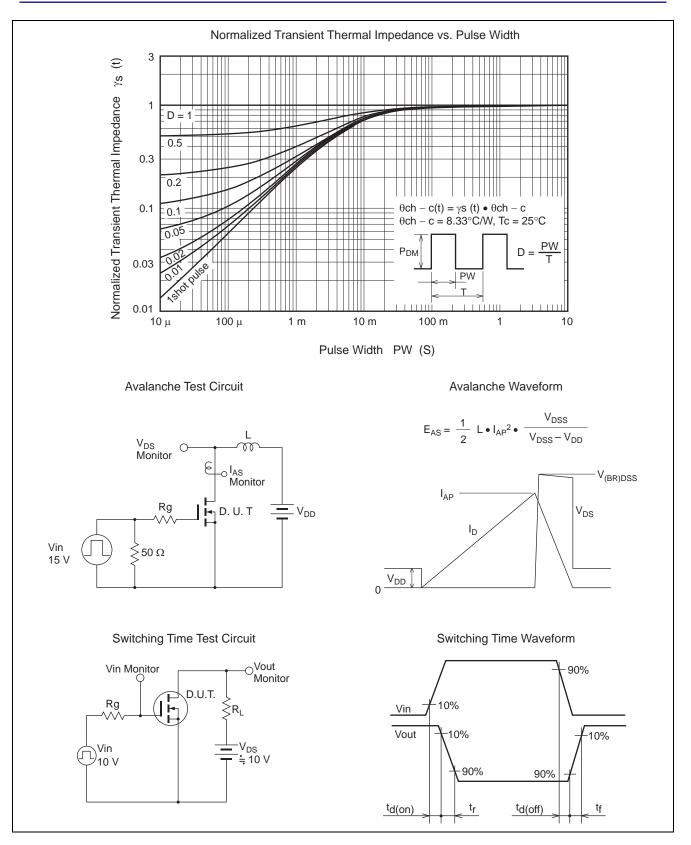
#### **Main Characteristics**



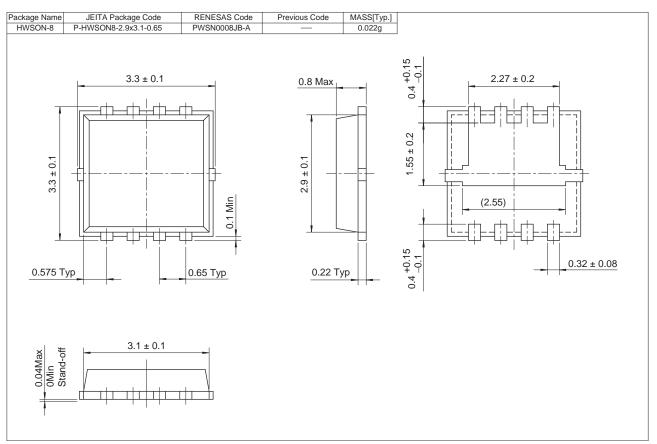








#### **Package Dimensions**



### **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK03L3DNS-00-J5	5000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".



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